B and - and k-dependent Self-Energy E ects in the U noccupied and O ccupied Q uasiparticle B and Structure of C u

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Excited-state self-energy e ects in the electronic structure of Cu, a prototype weakly correlated system containing states with di erent degrees of localization, are investigated with emphasis on the unoccupied states up to 40 eV above the Ferm i level. The analysis employs the experim ental quasiparticle states m apped under full control of the 3-dim ensional wavevectork using very-low energy electron di raction for the unoccupied states and photoem ission for the occupied states. The self-energy corrections to the density-functional theory show a distinct band- and k-dependence. This is supported by quasiparticle GW calculations perform ed within the fram ework of linearized mu n-tin orbitals. Our results suggest however that the GW approximation may be less accurate in the localized d-bands of C u with their short-range charge uctuations. W e identify a connection of the self-energy behavior with the spatial localization of the one-electron wavefunctions in the unit cell and with their behavior in the core region. Mechanisms of this connection are discussed based on the local-density picture and on the non-local exchange interaction with the valence states.

I. IN TRODUCTION

M any-body exchange-correlation e ects in the inhom ogeneous interacting electron system of solids, re ected by the quasiparticle E (k) band structure observed in the experiment, are still far from complete understanding. The standard D ensity Functional Theory (DFT) accounts for these e ects only in the ground state, yielding the static properties of the solids such as the charge density or the total energy. Of the DFT eigenvalues "(k), how ever, only the highest occupied one yields the correct excitation energy by a DFT analogue to the K oopm ans theorem,¹ while the others, strictly speaking, have no physical meaning as energy levels or excitation energies. D escription of the quasiparticle excited states, created by external photon, electron, etc. im pact, is by far m ore di cult (see, e.g., [2,3]). Their energies E (k) deviate from "(k) ow ing to the di erence of the excited-state dynam ic exchange-correlation potential, or the self-energy, from the ground-state static exchange-correlation potential $V_{X,C}$ used in the DFT. The form er is described by a complex energy-and k-dependent non-local self-energy operator , whose in aginary part Im describes the lifetime broadening of the excitation. Whereas for materials with strong localon-site correlations the excited-state many-body e ects are usually described by modelH am illonians, this approach cannot be extended to weakly correlated materials with long-range charge uctuations. Only a few perturbational low-order approaches, such as the GW approximation, $^{2;4;5}$ are suggested for this case.

Cu has since long been believed to be a prototype weakly-correlated m etal for which the DFT ground-state picture provides an accurate description of the excitation spectra (see, e.g., the review [6]). Only recently, based on comparison of new angle-resolved photoem ission (PE) data obtained under full control of the 3dim ensional wavevector k with state-of-art DFT calculations, we have dem onstrated that the self-energy corrections = E(k) "(k) to the DFT in the valence band of Cu display a clear k- and band dependence, reaching values as large as 0.5 eV in the d-bands.⁷ These results gave a serious indication for the importance of self-energy e ects even in such a supposedly simple metal as Cu. In fact, the previous m isconception had arisen only due to errors of the early DFT calculations which acciden-.⁸ Our prelim inary GW calculations⁹ tally matched have con med the general trends of the observed selfenergy behavior. The most recent GW calculations¹⁰ performed within the pseudopotential framework have yielded a striking agreem ent with the experim ental valence band of C u concerning the k-and band dependence ofthe shifts as well as their absolute values.

W hile the self-energy e ects in the valence band can be studied using PE spectroscopy, the unoccupied states still remain largely unexplored. Conventional spectroscopies of the upper states using X-ray absorption or B rem sstrahlung phenom ena¹¹ provide only k-integrated inform ation such as the matrix element weighted density of states. The k-resolving techniques such as inverse PE still involve two electron states and su er from uncertainties in the surface-perpendicular wavevector k_2 . Only recently it was realized that in the energy region above the vacuum level the quasiparticle E (k) can be mapped under full controlof the 3-dimensionalk using Very-Low – Energy Electron Di raction (VLEED) (see [7,12,13] and references therein). As the PE nal states are the timereversed LEED states,¹⁴ this inform ation can then be used in PE spectroscopy to achieve 3-dimensionalm apping of the valence band E (k).^{7;13}

Here, we extend the self-energy analysis to the unoccupied states in the energy region from the vacuum levelup to 40 eV above the Ferm i level E_F based on the VLEED experimental data. Contrary to a commonly accepted view, in this energy region the shifts also show a clear k-and band dependence. W e support our ndings by GW calculations perform ed within the fram ework of linearized mu n-tin orbitals, which include the valence and core states on equal footing. We show that the anom alies correlate with the spatial character of the oneelectron wavefunctions k, and endeavour to identify the essential physics of this. Our results on the valence band suggest that the GW approxim ation underestim ates the self-energy shifts due to the short-range charge uctuations characteristic of the d-bands of Cu.

II. EXPER IM EN TAL PROCEDURE AND RESULTS

O ur analysis em ploys the results of the recent V LEED and PE measurements performed on the Cu(110) surface.⁷ The information about the bulk band structure, rejected in the VLEED spectra, was insensitive to a slight oscillatory relaxation of this surface.¹⁵ This was con med by measurements on di errent surfaces⁷ as well as dynamical VLEED calculations.¹⁶

M apping of the unoccupied quasiparticle E (k) using VLEED (see [7,12,13] and the references therein) is based on the fact that the di raction process is connected with $E(k_2)$ along the Brillouin zone (BZ) direction determ ined by parallelm om entum conservation (external K_k = internal k_k). In particular, the extrem a in the di erential VLEED spectrum dT = dE of the elastic electron transmission relect the critical points (CPs) in the k_2 dispersions of the bands whose B loch wave k = cientlycouples to the incident plane wave. K k dispersion of the dT = dE extrem a, re ecting the CPs with k_2 lying on a surface-parallel symmetry line of the BZ, yields then E (k) along this line resolved in the 3-dimensionalk. In our case the angle-dependent V LEED data with K k varying in the \overline{Y} azimuth of the surface BZ yielded E (k) along the X line of the bulk $BZ.^7$

The direct mapping of the dT=dE extrem a re ects

however the CPs in the quasiparticle E (k) near the surface, corresponding to k excited by the VLEED beam and dam ped towards the crystal interior due to the nite electron lifetime, expressed by the electron absorption potential V_i = Im . Such E (k) is smoothed in k? (the dispersions in kk remain nevertheless unsm oothed by virtue of the surface-parallel invariance of the VLEED process) com pared to the quasiparticle E (k) in the bulk.^{7;12} The CPs appear as the points of extrem al (inverse) curvature of the the k₂ dispersions, and are intrinsically shifted from the corresponding CPs in the bulk E (k), recovered in the $V_{\rm i}=~0$ lim it, within a few tenths of eV. To improve the accuracy of evaluation, based on comparison with the DFT implying $V_i = 0$, we corrected our VLEED data from the Vi-induced shifts using a model calculation.

The model calculation employed the empirical pseudopotential method including V_i. E (k) and $_k$ with complex k₂ values were obtained by solving the Schrödinger-like equation

$$\frac{j^2}{2m}r^2 + V_{ps} \quad iV_i \quad k = E_k$$

where V_{ps} is the pseudopotential. The VLEED spectra were calculated within the matching approach (see details in [12]). In principle, matching calculations directly on top of the DFT calculations would be more straightforward, but this would require more complicated techniques such as the k p expansion¹⁷. In addition to the standard matching formalism, we included the surface barrier as an additional layer with a skewed-cosine like potential and perform ed m atching on the vacuum -barrier and barrier-crystal planes. Com pared to the step-like barrier, this improved the VLEED spectral structure en-0:3 eV. The shifts between the $V_i = 0 CPs$ ergies by and dT = dE extrem a, found in the model calculations, were then used to correct the experim entalpoints back to the $V_i = 0$ lim it to re ect the bulk E (k). This procedure also compensated the slight shifts of the VLEED spectral structures caused by the surface barrier and overlap of spectral structures.

The obtained unoccupied quasiparticle E (k) is shown in Fig.1 compared to the DFT and GW calculations (see below). The experim ental points reveal only the bands with signi cant coupling to vacuum, and others are not seen. We om itted the points where strong multiple-band hybridization e ects made it di cult to identify the CPs on the X line reliably. The lower X₁-point measured by VLEED on the Cu (100) surface¹⁸ is also added.

Here we will also scrutinize our previous results on the valence band E (k) from [7]. They are perfectly consistent with the whole body of previous experimental data compiled in [6], but have a superior accuracy by virtue of employing a combined VLEED PE method in which VLEED was used to achieve full control of the 3-dimensionalk. The experimental E (k) is shown in Fig 2 also compared with the calculations. The original data

from [7] was processed to include only the peaks relevant to the bulk states and compensate the lifetime induced intrinsic shifts of the PE peaks notable in the bottom of the sp-band (0:1eV). In principle, the accuracy of these data can be further in proved by correcting for possible intrinsic shifts due to the surface and m atrix element e ects, but this would require dem anding calculations within the one-step PE theory.¹⁴

III. D FT AND QUASIPARTICLE CALCULATIONS

OurDFT calculations used the Generalized Gradient Approximation $(GGA)^{19}$ for V_{XC} . For Cu the results were however alm ost indistinguishable from the LDA.A self-consistent full-potential linearized augmented plane wave (FLAPW) method implemented in the WIEN97 code²⁰ was used, with the basis extended by local orbitals to reduce the linearization errors in the extended energy region of the unoccupied states. Spin-orbit coupling was also included. It should be noted that now adays all stateof-art calculations on Cu agree within 100 m eV (at least in the valence band) which implies that the true DFT "(k) is achieved on this energy scale. The corrections to the PFT eigenvalues, given by the expecta- $_{k}$ ($V_{X C}$) $_{k} dr^{0}$ with the integration values R e tion over the unit cell , were calculated in the fram ework of the GW approximation.^{2;4;5} In this approximation the self-energy is given by²

$$(\mathbf{r};\mathbf{r}^{0};!) = \frac{i}{2}^{Z} d!^{0} e^{i!^{0}} G (\mathbf{r};\mathbf{r}^{0};!+!^{0}) W (\mathbf{r};\mathbf{r}^{0};!^{0})$$

In practical calculations, the G reen function G is approxim ated by a non-interacting one:

$$G(\mathbf{r};\mathbf{r}^{0};!) = \frac{X}{k} - \frac{k(\mathbf{r}) + k(\mathbf{r}^{0})}{k}$$

In our case, f $_{\rm k};"_{\rm k}g$ are the LDA-DFT wavefunctions and eigenvalues. The screened interaction W is given by $_7$

W
$$(r; r^{0}; !) = dr^{00}v (r r^{0})^{-1} (r^{00}; r^{0}; !)$$

where the dielectric matrix is calculated within the random-phase approximation without employing the plasm on-pole approximation. The present GW calculations employed one-electron calculations using the LDA exchange-correlation and the Linearized M u n-T in O rbitals - Atom ic Sphere Approximation (LMTO-ASA) method. In contrast to the pseudopotential framework, thism ethod allows to treat exchange-correlation with the core states on the sam e footing as the valence states. D etails of the computation may be found in [5]. The calculated values were added to the FLAPW eigenvalues whose computational accuracy at higher energies is better. The GW calculations on Cu are technically rather dem anding due to the presence of the d-states.

The results of the DFT and GW calculations are also shown in Figs.1 and 2.

IV . SELF-ENERGY CORRECTIONS

The unoccupied quasiparticle E (k) in Fig.1 deviate from the DFT results on the whole by 1 eV. However, the upper 1-band displays an anom alously large shift by as much as 2.8 eV. Near the bands are shifted also very unevenly. These anom alies, m issed in the previous studies,²¹ have been resolved here for the rst time by virtue of the single-state and k-resolving nature of VLEED. Reported previously,7;10;22 a peculiar renormalization relative to the DFT is also observed in the valence band in Fig 2, where the shifts of the sp-band (up to +0:4 eV in its bottom) and the d-bands (about 0:5 eV) even dier in sign. In the bottom of the dbands the deviations become smaller, which is due to hybridization of the d- and sp-bands.²³ Through the unoccupied and occupied states, the experim ental shifts from the DFT are thus intriguingly band-and k-dependent.

The deviations can have two sources. Firstly, the static $V_{X\ C}$ is not known exactly, and any DFT calculation has to resort to a reasonable approximation such as the GGA. However, the small di erence between LDA and GGA results and the excellent description of ground-state properties suggest that for Cu this problem is insigni – cant. The second, therefore predom inating, source is the excited-state self-energy e ects due to the di erence of the dynamic exchange-correlation from the static one $V_{X\ C}$. Our comparison of the experimental quasiparticle and DFT energies thus directly yields . The values in the X-point, corresponding in our experiment⁷ to K $_k=0$, are given in Table 1 compared to the GW calculations.

Inclusion of the dynam ic exchange-correlation within the GW approximation are seen to vastly improve description of the experimental excitation energies. In the unoccupied states the agreement is almost ideal, in particular for the anomalous shift in upper $_1$ -band, with the only clear exception in the $_{2^0}$ point. In the valence band the agreement is also excellent for the sp-band. In the d-bands the calculation correctly reproduces the sign of the shifts, although underestimates their magnitude. Interestingly, previous rst-principles many-body calculations on Cu using form alisms other than GW (see, e.g., [24]) failed to reproduce the behavior even qualitatively.

The observed self-energy anomalies in the unoccupied bands should be taken into account in LEED surface crystallography (see, e.g., [25]), which so far relied on a monotonous energy dependence of . In our case, for example, the observed shifts of the VLEED spectral structures would be interpreted as due to a surface relaxation, but they are only due to the band- and kdependent self-energy behavior. The observed excellent relevance of the GW approximation for the unoccupied states suggests to use it in LEED crystallography.

V.MECHANISMS OF THE SELF-ENERGY BEHAVIOR

A lthough the observed self-energy behavior is well reproduced by the GW calculations, their physical mechanism s rem ain obscured by the heavy computational machinery. We will now endeavour to identify the possible mechanism s, at least on a qualitative level.

A . Local-density picture

The observed anomalies in $\ can be traced back$ to di erent spatial localization (SL) of the one-electron B loch waves $_k$, i.e. the distribution of their weight within the unit cell. Such a mechanism was originally suggested in [22]. It assumes the local-density concept, i.e. neglects the non-locality of $\ .$

We start with a discussion of the behavior in the hom ogeneous electron gas. The dynam ic exchangecorrelation as function of momentum k and electron density n was calculated for this model system by Hedin and Lundquist.²⁶ From their data we derived as the di erence of to its value at the Ferm i wavevector k $_{\rm F}$, which, by the DFT analogue to the K copm ans theorem ,¹ is essentially the static $V_{\rm X\,C}$. The resulting dependencies of on E =E $_{\rm F}$ are shown in Fig.3 (left). The crucial parameter to determ ine their behavior is the electron density.

In real crystals the electron density is inhom ogeneous. The electron gas plasm on dip in is damped (dashed line) by averaging over the varying local density n (r) and by interband transitions. Most importantly, as shown in Fig.3 (right), the electron density { and consequently { experienced by a one-electron wavefunction depends now on its spatial localization: if $_k$ has large weight in the core region where n (r) is high, it will experience a large-density energy dependence of , characterized by a strong repulsion from E $_F$. If $_k$ expands well into the interstitial region with low n (r), it will experience a small-density dependence with its smaller

repulsion from E $_{\rm F}$. Such an SL mechanism goes beyond the usual wavefunction localization e ect (see, e.g., [27]) as not only the strength of the localization (m easured by the bandwidth) m atters but also the region of its localization.

In the valence band of C u the SL mechanism has certainly some relevance (see also [22]): The d-bands localized in the high-density core region experience large effective density and, re ecting the behavior in Fig.3, shift lower in energy, whereas the sp-band with its charge spread out into the low-density interstitial region experiences sm all e ective density and shifts in the opposite direction. A qualitative support of this picture was obtained by calculating the e ective densities $h_k jn(r) j_k i$ (see [9]), which well correlate with the experimental values both in the d- and sp-bands. Exclusion of the core states from the totaln (r) did not a ect the correlation. However, the SL mechanism alone can not provide any quantitative description of the self-energy behavior mainly due to neglect of the non-locality of the operator. Indeed, the corresponding calculation²² returned an unrealistic plasm on dip of in the unoccupied bands and, although properly reproducing the sign of the shifts in the valence band, severely underestim ated their m agnitude.

In the unoccupied states, the SL mechanism could not be reconciled with the experimental self-energy anomaly in the upper 1-band even qualitatively unless we included into n (r) all core states down to the 1s state having a binding energy of 9 keV. Any signicant e ect of such a deep level on the dynamic exchange-correlation within the local density picture seems unrealistic. This hints on an extrem ely non-local mechanism of interaction with the core states, as we discuss below.

B.GW picture

We will now analyze a connection between $_{k}$ and the self-energy e ects within the GW framework, taking into account the non-locality of the operator acting as $_{k} = (r;r^{0}) _{k} (r^{0}) dr^{0}$. First, we introduce a local quantity (r) comprising local contributions to , obtained by integrating out the non-locality of as

Z

 $(r) = {}_{k} f (r; r^{0}) V_{X C} (r) (r r^{0})g_{k} (r^{0}) dr^{0}$

Integration of (r) over the unit cell with the weight / r^2 gives the total self-energy correction

$$= 4 r^{2}$$
 (r) dr

The calculated $j_k j_{\ell}$, (r) and r 2 -weighted (r) for the valence and unoccupied states in the X -point, obtained within the GW fram ework, are shown in Fig.4. We note, rstly, that the total is always form ed by a balance between positive local (r) values in the core region and negative values in the interstitial region (which is seen better in the r^2 (r) curves). Such a behavior of (r) is in fact general. Indeed, if is assumed_bto be diagonal in the LDA Bloch basis as $(r;r^{0}) =$ k = k (r) k = k (r⁰), from the above equation

(r) $(_{k} V_{XC} (r)) j_{k} j^{2}$

In the core region (sm all r) the negative $V_{X,C}$ blows up, forcing (r) to become large and positive in this region. _k, determ ined by the particular _k, acts as a constant

we obtain

negative o set. In the interstitial region (large r) $V_{X\ C}$ decreases and $_k$ forces (r) to become negative. In our case the o-diagonal elements of are small, and such a pattern holds well for all states despite strong variations in the character of $_k$.

At rst glance, the SL mechanism seems to revive in this picture, with an amendment that the gure of merit is in fact the weight of $_k$ in the core region rather than that in the high-density region (these two can somewhat di er). Indeed, if the weight of $_k$ shifts into the core region, the positive contribution would increase and the quasiparticle level would shift higher in energy. How-ever, this is much hampered by the $_k$ o set, which is also sensitive to the character of $_k$ in a highly involved manner.

In view of the limitations of the SL mechanism, another mechanism of the observed self-energy behavior can be suggested. Fig.4 shows that the valence and two unoccupied X₁-states are di erent from others in that their $_k$ has a large 4s component, blow ing up at the nucleus (r = 0). These { and only these { states experience an anom alous positive shift on top of the general trend that the repulsion from E $_{\rm F}$ graually increases upon going away from E $_{\rm F}$.

To extend this observation to other points in the BZ, we scrutinized the FLAPW calculations to determ ine the 4s projections (partial 4s charges) of k inside the atom ic spheres, which are given by coe cients in the expansion $_{\rm lm}$ A $_{\rm lm}$ u $_{\rm lm}\,$ (r) Y $_{\rm lm}\,$ (;). The calculated 4s pro-_k = jections are shown in Fig.5. Their comparison with the experimental results in Figs.1 and 2 demonstrates that the anom alous positive correspond everywhere to the 1-states having large 4s character. M oreover, in Fig.6 we show the experimental values as a function of energy and the 4s projections for the whole X line. Again, the anom alous positive on top of a regular energy dependence correlate everywhere with the large 4s character of k, with the only clear exception in the 250-point.

The observed connection can not be explained within the above local picture, because the r^2 -weighting cancels the contribution of (r) from the nucleus region to the total , see Fig.4. Moreover, other states such as X $_{5^0}$ and X $_{4^0}$, which have even more total weight in the high-density region than the states with the 4s character, can nevertheless not experience anom alous positive . The observed connection can only manifest a non-local exchange-correlation e ect, acting through the $_k$ o set in the (r) dependence.

In the following we propose a qualitative explanation for the above anom abus behaviour. Let us focus ourselves on the states X $_{5^0}$;X $_3$ and X $_1$ which have almost the same correlation energy $_{\rm C}$, as can be seen in Table 2. It implies that di erences in the self-energy shifts can only be due the di erences in the exchange energy $_{\rm X}$ and V $_{\rm X \ C}$. The trend in

$$X = X^{2}$$

$$X = k^{2} (r) (r) (r) (r) (r) (r) (r) (r^{0}) (r$$

where q spans the occupied states, can be understood by analyzing the character of the states. Indeed, the X $_{5^0}$ state, which has a large 4p character, has the sm allest x among the three states. This is because the occupied states have very little 4p character, which makes the above exchange integral sm all. The X₃-state, on the other hand, has a signi cant 3d character, which gives a large exchange with the occupied 3d bands resulting in the largest x. The X_1 -state, the anom alous one, has a large 4s character but the occupied 4s valence states are plane-wave like so that x is somewhere in between those of the X 50-state and X 3-state. The trend in $V_{X\ C}$ seems clear from the charge distribution of the states, with the X₃-state being the most localized inside the mun-tin sphere. The physical picture arising from this qualitative analysis is that the X₁-state has an anom alously large shift because it has a large 4s character, which makes its exchange relatively small, and at the same time its charge distribution has a large weight inside the mu n-tin sphere where the exchange-correlation potential is deep, which makes V_{X C} large. These two effects result in a large self-energy shift. W e note that the amount of 4s character alone is probably insu cient to m ake a quantitative connection to the self-energy correction. For example, the lower unoccupied X₁-state is less anom alous although it has a large 4s character too. This can be understood from the fact that it has a signi cant 3d character (Fig.5), which increases the amount of exchange and reduces the self-energy shift. Such an e ect of the 3d character is consistent with the negative shifts of the valence 3d bands. M oreover, our qualitative picture neglects the exchange-correlation with the core levels, while the recent GW calculations¹⁰ suggest that the contribution of the 3s and 3p levels is signi cant.

The exchange contribution from the valence states, connected with the wavefunction character, explains therefore the self-energy anomalies on top of the SL m echanism. In the unoccupied states of C u the exchange contribution becom es critical.

VI.IS THE GW APPROXIMATION ACCURATE FOR THE LOCALIZED ORBITALS?

The recent GW calculation by M arini et al_r^{10} perform ed within the pseudopotential fram ework, have demonstrated a good agreem ent with the experimental valence band of C u both on the delocalized sp-band and the localized d-bands. They conluded that the GW approximation, originally proposed to describe long-range charge oscillations, well extends to the localized orbitals and short-range correlations found in Cu.

OurGW results are som ew hat di erent how ever. They also dem onstrate alm ost ideal agreem ent with the experim ent on the delocalized bands such as the valence

sp-band, but on the localized d-bands they tend to underestim ate the negative shifts (see also Table 1). Interestingly, both calculations yield a wrong sign of in the bottom of the d-bands where they hybridize with the sp-band. Com pared to the pseudopotential fram ework, our LM TO -A SA calculations have two fundam entaladvantages: 1) use of the true one-electron wavefunctions rather than pseudow avefunctions; 2) explicit inclusion of all core states, not only the 3s and 3p states as in [10]. Another recent GW calculation based on the fullpotential LM TO²⁸ also yielded sm all shifts in the d-bands. The deviations from the experim ent, rem aining in the d-bands, would therefore indicate certain shortcom ings of the GW approximation in the description of localized orbitals and short-range correlations. How ever, any unambiguous conclusions on this point require further analysis, because the observed m ism atch between dierent GW calculations is comparable with their numerical accuracy.

VII.OTHER MATERIALS

Experimentalk-resolved data on the self-energy e ects in the unoccupied bands of other materials is still scarce. In graphite²⁹ we have found only a small and regular

shift to higher energies (0.1 to 0.5 eV relative to the GGA-DFT) which however notably increased above a distinct absorption threshold at 35 eV. A similar situation has been found in NbSe₂.¹⁷ Such an increase is not surprising, because the energy dependence of R e is linked to that of Im via the K ram ers-K ronig relations. Interestingly, it was not reproduced by GW calculations. In the valence band of graphite³⁰ we have identi ed the SL m echanism to cause di erent shifts of the - and

-states, having di erent overlap with the in-plane oriented valence electron density. In [31,32] it was speculated that widening of the valence band in graphite and other non-m etals could result from electron localization in high-density regions, in agreement with the SL mechanism.

The unoccupied bands of N i^{33} feature anomalies resembling those of Cu. It seems that they are typical for noble m etals. The valence band of N i (see, e.g., [34] and references therein) is characterized by a narrowing of the d-bands (shifts towards E F) which is opposite to Cu. This self-energy e ect has a di erent origin - strong on-site correlations in the partially led d-shell. The narrowing of the sp-band is how ever sim ilar to Cu. Interestingly, in [23] the k-dependence of in the whole valence band was decom posed into constant contributions from the sp-and d-bands whose weight was determ ined only by the band hybridization. N arrowing of delocalized bands has also been observed for simple m etals like N a.³⁵

V III. C O N C LU S IO N

Excited-state self-energy e ects in the unoccupied and valence band electronic structure of C u were investigated. The unoccupied quasiparticle bands in the energy region up to 40 eV above $E_{\rm F}$ are for the $\mbox{rst time mapped}$ under full control of the 3-dim ensionalk using VLEED. They dem onstrate, sim ilarly to the valence bands, a signi cant band- and k-dependence of the self-energy corrections to the DFT. The observed behavior in the unoccupied and valence bands correlates with the spatial localization of the one-electron wavefunctions in the unit cell, and with their behavior in the core region expressed by the 4s and 3d projections. These e ects are described, correspondingly, by the spatial localization m echanism based essentially on the local-density picture, and by the non-local exchange interaction with the valence states. In the unoccupied bands of C u the latter is particularly important. Our GW quasiparticle calculations perform ed within the LM TO -ASA fram ework yield alm ost ideal agreem ent with the experim ent on the delocalized bands such as the unoccupied and valence spbands, but on the localized d-bands they underestim ate the shifts. This may indicate certain limitations of the GW approximation applied to the localized orbitals and short-range correlations. The observed band- and k-dependent self-energy e ects in the unoccupied bands have an important implication in LEED studies of the surface crystallography.

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TABLE I. The DFT eigenvalues in the X-point and the corresponding corrections: experiment ($_{EXP}$), our GW calculations using LM TO-ASA ($_{GW LM TO}$), and GW calculations using the pseudopotential scheme ($_{GW PP}$) from [10]. Energies are in eV relative E_F.

	E _{DFT FLAPW}	EXP	GW LMTO	GW PP
Χ1	20.34	2.44	2,51	
Х з	17.63	0.45	0.43	
X 50	12.98/13.16	0.77/0.59	0.68	
Χ1	7.13	0.54	0.81	
X 40	1.39		0.20	
Χ ₅	-1.55/-1.39	-0.44/-0.60	-0.26	-0.64
X 2	-1.68	-0.50	-0.47	
Х ₃	-4.51	-0.34	0.05	0.10
Χ1	-4.98	-0.29	0.13	0.16

TABLE II. The exchange and correlation energies for unoccupied bands in the X -point. All energies are in eV .

	E _{DFT FLAPW}	x	С	V _{xc}	
X 1	20.34	-10.07	-5.89	-19.83	
Х з	17.63	-14.91	-5.90	-22.46	
X 50	12.98/13.16	-6.64	-5.68	-14.19	
Χ 1	7.13	-18.10	-3.45	-23.74	
X 40	1.39	-10.48	-2.18	-13.92	

FIG.1. VLEED quasiparticle unoccupied bands (dots) compared to the DFT "(k) (solid lines). The deviations reveal the band- and k-dependent excited-state self-energy effects. The bands with su cient coupling to the vacuum are marked by gray shading. The quasiparticle GW calculations are shown by open circles.

FIG.2. PE quasiparticle valence band compared to the DFT "(k) and to the GW calculations similarly to Fig.1.

FIG.3. Mechanism of the spatial localization e ect: (left): for the free electron gas. Its behavior depends on the electron density. (right): In real crystals a wavefunction concentrated in the core region experiences a high e ective density, whereas larger weight in the interstitial region (exaggerated, in reality this case in plies a more hom ogeneous distribution) leads to a low er density. This results in di erent behavior.

FIG. 4. $j_k j^2$ and GW calculated local (r) and r^2 -weighted (r) for the unoccupied and valence states in the X-point. Note the change in the r scale at 0.1 a.u. The curves are norm alized to set their variation to 1. (r) is positive in the core region and negative in the interstitial region. The X₁ states with the anom alous positive values have the 4s character.

FIG.5. Calculated 4s and 3d character of $_{\rm k}$, expressed by the corresponding projections within the atom ic spheres (in electrons), and represented by the size of the circles.

FIG.6. Experimental vs the DFT energy and 4s character of $_k$ from Fig.5, represented by the size of the vertical bars. The dashed line is a guide for the eye showing a regular energy dependence of for the states with negligible 4s character. The anom alous positive values correlate with the 4s character of the one-electron states.



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Fig.2byStrocov et al



Fig.3byStrocov et al





Fig.5byStrocov et al



Fig.6byStrocov et al